

2N5302G

2N5302G Information



Part Number	2N5302G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
Description	TRANS NPN 60V 30A TO3
Package	TO-204AA, TO-3
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2N5302G Specifications

Manufacturer Part Number	2N5302G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
Category	
	Transistors - Bipolar (BJT) - Single
Package	ТО-204АА, ТО-3
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	30A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	3V @ 6A, 30A
Current - Collector Cutoff (Max)	5mA
DC Current Gain (hFE) (Min) @ Ic, Vce	15 @ 15A, 2V
Power - Max	200W
Frequency - Transition	2MHz
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-204AA, TO-3
Supplier Device Package	TO-3
	Report errors?

2N5302G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about 2N5302G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com